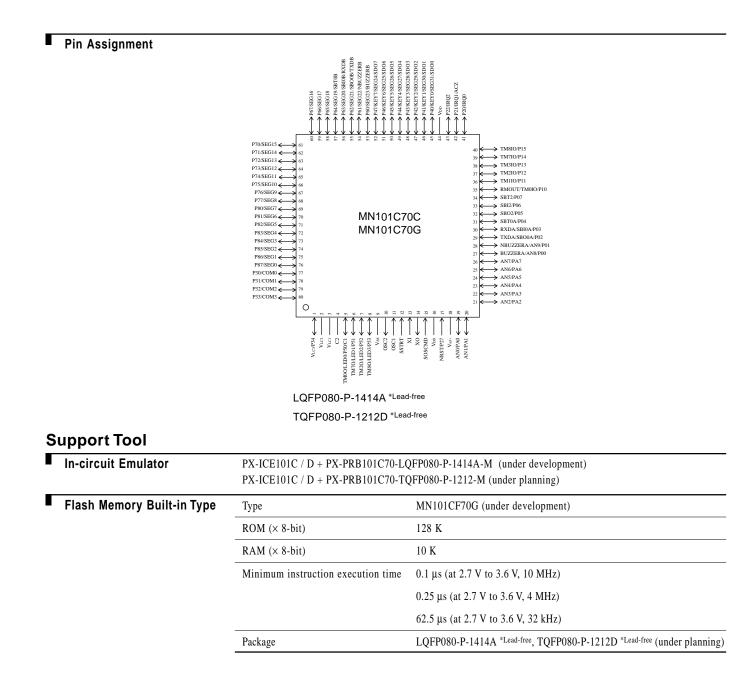
□ MN101C70C, MN101C70G

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Туре	MN101C70C(under development)	MN101C70G(under planning)					
ROM (×8-bit)	48 K	128 K					
RAM (×8-bit)	2 K	10 K					
Package	LQFP080-P-1414A *Lead-free, TQFP080-P-1212D *Lead-free						
Minimum Instruction Execution Time	0.1 μs (at 2.7 V to 3.6 V, 10 MHz) 0.5 μs (at 1.8 V to 3.6 V, 4 MHz) 62.5 μs (at 1.8 V to 3.6 V, 32 kHz)						
Interrupts	 RESET • Watchdog • External 0 • External 1 • External 2 • External 4 (key interrupt dedicated) • Timer 0 Timer 1 • Timer 2 • Timer 3 • Timer 6 • Time base • Timer 7 (2 systems) • Timer 8 (2 systems) Serial 0 (2 systems) • Serial 2 • A/D conversion finish • Automatic transfer finish 						
Timer Counter	Timer counter 0 : 8-bit × 1 (square-wave/8-bit PWM output, event count, generation of remote control carrier, simple pulse width measurement) (square-wave/PWM output to large current terminal P50 possible) Clock source						
	Timer counter 1 : 8-bit × 1 (square-wave output, event count, synchronous output event) Clock source						
	Timer counter 0, 1 can be cascade-connected.						
	Timer counter 2 : 8-bit × 1 (square-wave output, additional pulse type 10-bit PWM output, event count, synchronous output event, simple pulse width measurement) (square-wave/PWM output to large current terminal P52 possible) Clock source						
	Timer counter 3 : 8-bit × 1						
	(square-wave output, event count, generation of remote Clock source 1/2, 1/8 of system clocl oscillation clock freque clock input	k frequency; 1/1, 1/4, 1/16, 1/64, 1/128 of OSC ency; 1/1 of XI oscillation clock frequency; external					
	Interrupt source coincidence with compa	are register 3					
	Timer counter 2, 3 can be cascade-connected.						
	-	quency; 1/1, 1/128, 1/8192 of OSC oscillation clock 1/8192 of XI oscillation clock frequency are register 6					
	Timer counter 7 : 16-bit × 1 (square-wave output, 16-bit PWM output (cycle / duty evevt, pulse width measurement, input capture) (square possible) Clock source 1/1, 1/2, 1/4, 1/16 of sy oscillation clock freque Interrupt source coincidence with compa	e-wave/PWM output to large current terminal P51 estem clock frequency; 1/1, 1/2, 1/4, 1/16 of OSC ency; 1/1, 1/2, 1/4, 1/16 of external clock input frequency					

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Timer Counte	r Time	r counter 8:	16 bit × 1							
(Continue)		(square-wave/16-bit PWM output [duty continuous variable], event count, pulse width measurement, input capture) (square-wave/PWM output to large current terminal P53 possible) Clock source								
		-	t source coincidence with compare register 8 (2 lines	5)						
		Timer counters 7, 8 can be cascade-connected. (square-wave output, PWM, input capture, pulse width measurement is possible as a 32-bit timer.)								
	Tim	Time base timer (one-minute count setting) Clock source 1/1 of OSC oscillation clock frequency; 1/1 of XI oscillation clock frequenc Interrupt source 1/128, 1/256, 1/512, 1/1024, 1/8192, 1/32768, of clock source frequency								
	Wate	Watchdog timer Interrupt source 1/65536, 1/262144, 1/1048576 of system clock frequency								
Serial Interface	e Seria	Serial 0 : synchronous type/UART (full-duplex) × 1 Clock source								
	Seria	-	onous type/single-master $I^2C \times 1$ purce 1/2, 1/4 of system clock frequency; pulse of 1/2, 1/4, 1/16, 1/32 of OSC oscillation clock	•		iter 2 or 3	;			
I/O Pins	I/O 66	66 • Common use • Specified pull-up resistor available • Input/output selectable (bit unit)								
A/D Inputs	10-b	t × 16-ch. (with S/H)							
LCD	LCD LCD	32 segments × 4 commons (static, 1/2, 1/3, or 1/4 duty) LCD power supply separated from VDD (usable if VDD ≤ VLCD ≤ 3.6 V) LCD power step-up circuit contained (3/2, 2 and 3 times) LCD power shunt resistance contained								
Special Ports		Buzzer output, remote control carrier signal output, high-current drive port								
Electrical Char Supply curren										
D				Limit						
Paramet	ter Sym		Condition	min	typ	max	Un			
	IDI	1	fosc = 4 MHz, VDD = 3 V		1	2	m			
Operatingsupplycu	Irrent IDI	2	fx = 32 kHz, VDD = 3 V		8	20	μ			
C	IDI	3	$fx = 32 \text{ kHz}, \text{VDD} = 3 \text{ V}, \text{ Ta} = 25^{\circ}\text{C}$		3	7	μ			
Supply current at H/	IDI	4	fx = 32 kHz, VDD = 3 V, Ta = -40° C to $+85^{\circ}$ C			25	μ			
Supply or mont of O	IDI	5	$VDD = 3 V, Ta = 25^{\circ}C$			2	μ			
Supply current at S	IDI	6	$VDD = 3 V$, $Ta = -40^{\circ}C$ to $+85^{\circ}C$			20	μ			



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